



AMP2086BP SOLID STATE HIGH POWER AMPLIFIER

FEATURES

- Class AB linear GaN design
- Rack mounted system
- Instantaneous ultra-wide bandwidth
- Suitable for broadband EMI/RFI, Lab, Comm. and EW applications
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	500 - 3000 MHz	
Power Output Pulse	200 Watt Min	
Pulse Characteristics	Width	
	50 μS	
	Duty	
	5 %	
Power Gain	53 dB Min	
Power Gain Flatness	4.0 dB p-p Max	Constant input power
Input / Output Return Loss	-10 dB Max	Relative to 50 Ohm
Harmonics	-20 dBc Typ	At rated output power
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	100 - 240 VAC	
Power Consumption	400 Watt	At rated Pout
Input Power Protection	+8 dBm Max	>10 Sec without damage
Load VSWR Protection	∞ : 1	>1 Minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 133 x 560 mm	R3U - Excluding handles
Weight	20 kg.	
RF Connectors In / Out	Type-N Female	
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	Variable speed
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485 Optional GPIB Interface	Remote Bluetooth application

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OUTLINE DRAWING

